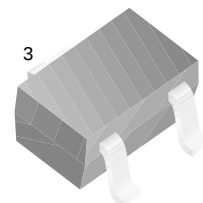


FJX1182

FJX1182

Low Frequency Power Amplifier



1 SOT-323
1. Base 2. Emitter 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	-35	V
V_{CEO}	Collector-Emitter Voltage	-30	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current	-500	mA
P_C	Collector Power Dissipation	150	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

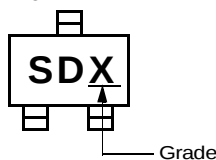
Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
I_{CBO}	Collector Cut-off Current	$V_{CB} = -35, I_E = 0$			-0.1	μA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = -5V, I_C = 0$			-0.1	μA
h_{FE1} h_{FE2}	DC Current Gain	$V_{CE} = -1V, I_C = -100\text{mA}$ $V_{CE} = -6V, I_C = -400\text{mA}$	70 25		240	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -100\text{mA}, I_B = -10\text{mA}$		-0.1	-0.25	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = -100\text{mA}, V_{CE} = -1V$		-0.8	-1.0	V
f_T	Current Gain Bandwidth Product	$I_C = -20\text{mA}, V_{CE} = -6V$		200		MHz
C_{ob}	Output Capacitance	$V_{CB} = -6V, I_E = 0$ $f = 1\text{MHz}$		13		pF

h_{FE} Classification

Classification	O	Y
h_{FE1}	70 ~ 140	120 ~ 240

Marking



Typical Characteristics

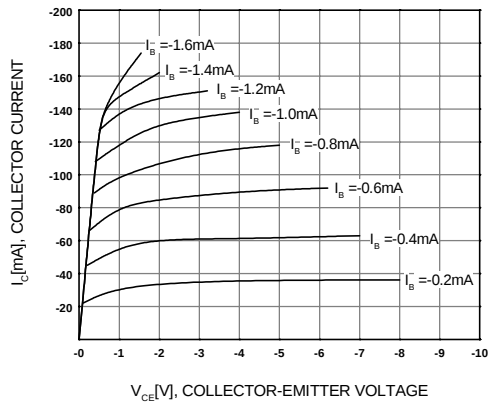


Figure 1. Static Characteristic

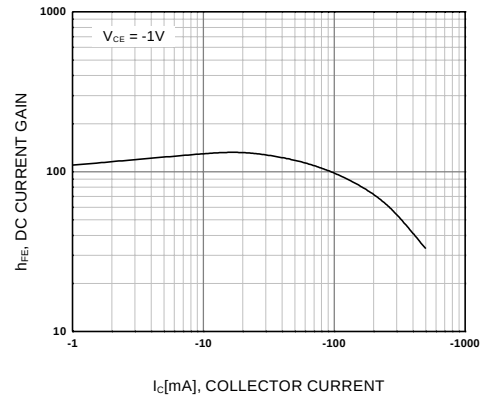


Figure 2. DC current Gain

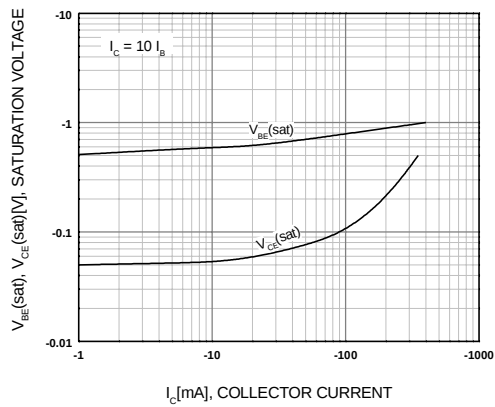


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

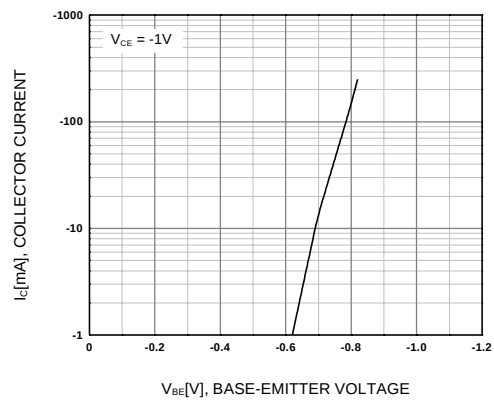


Figure 4. Base-Emitter On Voltage

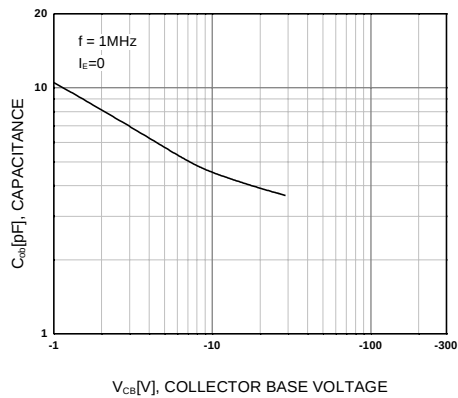
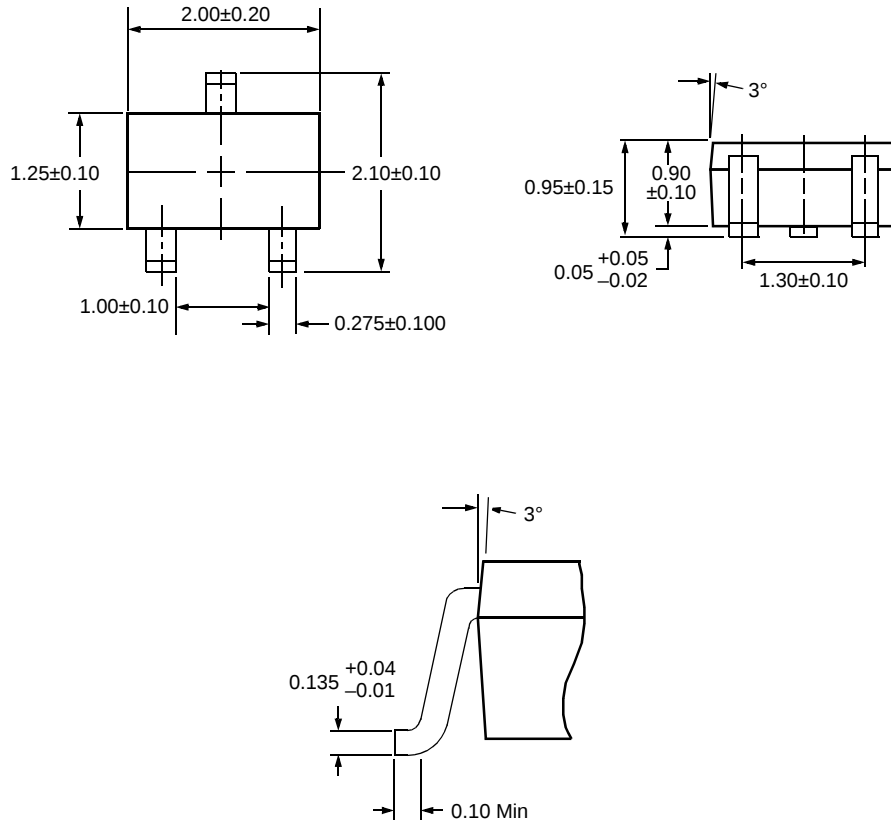


Figure 5. Collector Output Capacitance

Package Dimensions

SOT-323



Dimensions in Millimeters

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